

ISC Silicon NPN Power Transistor

BDY60

DESCRIPTION

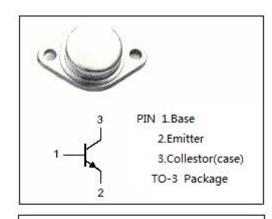
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO} = 60V (Min)
- Low Collector-Emitter Saturation Voltage
- Excellent Safe Operating Area
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

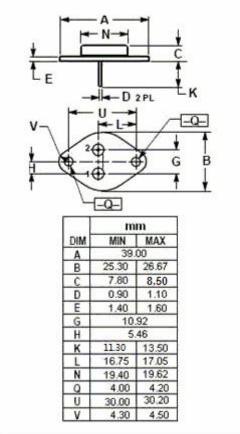
APPLICATIONS

Designed for power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|-------------------------------------|---------|------------|
| V _{СВО} | Collector-Base Voltage | 120 | V |
| V_{CEO} | Collector-Emitter Voltage | 60 | V |
| V _{EBO} | Emitter-Base Voltage | 7 | V |
| lc | Collector Current-Continuous | 5 | Α |
| I _{CM} | Collector Current-Peak | 8 | Α |
| I _B | Base Current-Continuous | 3 | Α |
| Pc | Collector Power Dissipation @Tc=25℃ | 50 | W |
| TJ | Junction Temperature | 150 | $^{\circ}$ |
| T _{stg} | Storage Temperature | -65~150 | $^{\circ}$ |







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | Ic= 10mA; I _B = 0 | 60 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = 1mA ; I _C = 0 | 5 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 4A; I _B = 0.4A | | | 2.0 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 1A; V _{CE} = 5V | | | 1.5 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 120V ; I _E = 0 | | | 100 | μА |
| ІЕВО | Emitter Cutoff Current | V _{EB} = 5V ; I _C = 0 | | | 100 | μА |
| h _{FE-1} | DC Current Gain | I _C = 1A; V _{CE} = 2V | 40 | | 300 | |
| h _{FE-2} | DC Current Gain | I _C = 4A ; V _{CE} = 2V | 20 | | | |
| f⊤ | Current-Gain—Bandwidth Product | I _C = 1A; V _{CE} = 5V | 30 | | | MHz |

NOTICE:

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